

## Algorithm for Wavefront Sensing Using an Extended Scene

The restriction to a point source has been removed.

NASA's Jet Propulsion Laboratory, Pasadena, California

A recently conceived algorithm for processing image data acquired by a Shack-Hartmann (SH) wavefront sensor is not subject to the restriction, previously applicable in SH wavefront sensing, that the image be formed from a distant star or other equivalent of a point light source. That is to say, the image could be of an extended scene. (One still has the option of using a point source.) The algorithm can be implemented in commercially available software on ordinary computers.

The steps of the algorithm are the following:

1. Suppose that the image comprises  $M$  sub-images. Determine the  $x,y$  Cartesian coordinates of the centers of these sub-images and store them in a  $2 \times M$  matrix.
2. Within each sub-image, choose an

$N \times N$ -pixel cell centered at the coordinates determined in step 1. For the  $l$ th sub-image, let this cell be denoted as  $s_l(x,y)$ . Let the cell of another sub-image (preferably near the center of the whole extended-scene image) be designated a reference cell, denoted  $r(x,y)$ .

3. Calculate the fast Fourier transforms of the sub-sub-images in the central  $N \times N$  portions (where  $N < N$  and both are preferably powers of 2) of  $r(x,y)$  and  $s_l(x,y)$ .
4. Multiply the two transforms to obtain a cross-correlation function  $C_l(u,v)$ , in the Fourier domain. Then let the phase of  $C_l(u,v)$  constitute a phase function,  $\phi(u,v)$ .
5. Fit  $u$  and  $v$  slopes to  $\phi(u,v)$  over a small  $u,v$  subdomain.
6. Compute the fast Fourier transform,  $S_l(u,v)$  of the full  $N \times N$  cell  $s_l(x,y)$ . Mul-

tiple this transform by the  $u$  and  $v$  phase slopes obtained in step 4. Then compute the inverse fast Fourier transform of the product.

7. Repeat steps 4 through 6 in an iteration loop, cumulating the  $u$  and  $v$  slopes, until a maximum iteration number is reached or the change in image shift becomes smaller than a predetermined tolerance.
8. Repeat steps 4 through 7 for the cells of all other sub-images.

This work was done by Erkin Sidick, Joseph Green, Catherine Ohara, and David Redding of Caltech for NASA's Jet Propulsion Laboratory. Further information is contained in a TSP (see page 1).

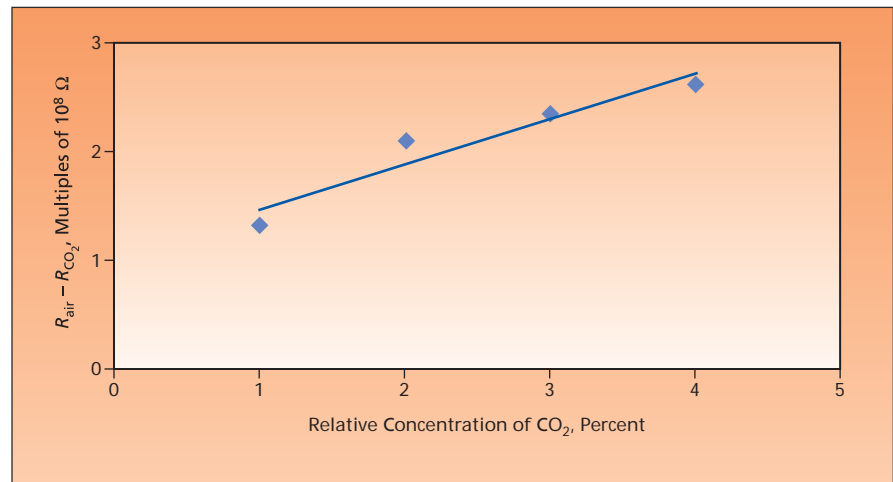
The software used in this innovation is available for commercial licensing. Please contact Karina Edmonds of the California Institute of Technology at (626) 395-2322. Refer to NPO-44770.

## CO<sub>2</sub> Sensors Based on Nanocrystalline SnO<sub>2</sub> Doped With CuO

Miniature CO<sub>2</sub> sensors could be mass-produced inexpensively.

John H. Glenn Research Center, Cleveland, Ohio

Nanocrystalline tin oxide (SnO<sub>2</sub>) doped with copper oxide (CuO) has been found to be useful as an electrical-resistance sensory material for measuring the concentration of carbon dioxide in air. SnO<sub>2</sub> is an n-type semiconductor that has been widely used as a sensing material for detecting such reducing gases as carbon monoxide, some of the nitrogen oxides, and hydrocarbons. Without doping, SnO<sub>2</sub> usually does not respond to carbon dioxide and other stable gases. The discovery that the electrical resistance of CuO-doped SnO<sub>2</sub> varies significantly with the concentration of CO<sub>2</sub> creates opportunities for the development of relatively inexpensive CO<sub>2</sub> sensors for detecting fires and monitoring atmospheric conditions. This discovery could also lead to research that could alter fundamental knowledge of SnO<sub>2</sub> as a sensing material, perhaps leading to the development of SnO<sub>2</sub>-based sensing materials for measuring concentrations of oxidizing gases.



The Electrical Resistance of a 1:8 CuO:SnO<sub>2</sub> film fabricated as described in the text was found to decrease as the concentration of CO<sub>2</sub> in air increased.  $R_{\text{air}}$  signifies the resistance of the film in pure air;  $R_{\text{CO}_2}$  signifies the resistance of the film at the indicated concentration of CO<sub>2</sub>.

Prototype CO<sub>2</sub> sensors based on CuO-doped SnO<sub>2</sub> have been fabricated by means of semiconductor-microfabrication and sol-gel nanomaterial-synthesis batch processes that are amendable to

inexpensive implementation in mass production. A fabrication process like that of the prototypes includes the following major steps:

1. Platinum interdigitated electrodes are